

DG411/412/413

Vishay Siliconix

Precision Monolithic Quad SPST CMOS Analog Switches

DESCRIPTION

The DG411 series of monolithic quad analog switches was designed to provide high speed, low error switching of precision analog signals. Combining low power (0.35 μ W) with high speed (t_{ON}: 110 ns), the DG411 family is ideally suited for portable and battery powered industrial and military applications.

To achieve high-voltage ratings and superior switching performance, the DG411 series was built on Vishay Siliconix's high voltage silicon gate process. An epitaxial layer prevents latchup.

Each switch conducts equally well in both directions when on, and blocks input voltages up to the supply levels when off.

The DG411 and DG412 respond to opposite control logic as shown in the Truth Table. The DG413 has two normally open and two normally closed switches.

FEATURES

- 44 V Supply Max Rating
- ± 15 V Analog Signal Range
- On-Resistance r_{DS(on)}: 25 Ω
- Fast Switching t_{ON}: 110 ns
- Ultra Low Power P_D : 0.35 μ W
- TTL, CMOS Compatible
- Single Supply Capability

BENEFITS

- Widest Dynamic Range
- Low Signal Errors and Distortion
- Break-Before-Make Switching Action
- Simple Interfacing

APPLICATIONS

Precision Automatic Test Equipment

TRUTH TABLE

Logic

0

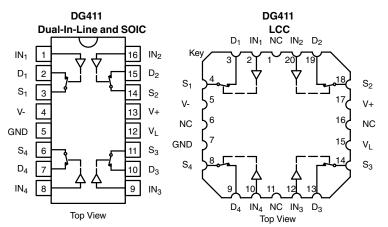
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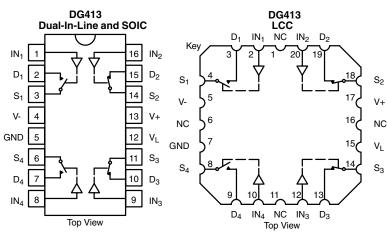
Logic "0" \leq 0.8 V

Logic "1" ≥ 2.4 V

- Precision Data Acquisition
- Communication Systems
- Battery Powered Systems
- · Computer Peripherals

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION





* Pb containing terminations are not RoHS compliant, exemptions may apply

 Logic
 SW1, SW4
 SW2, SW3

 0
 OFF
 ON

 1
 ON
 OFF

DG411

ON

OFF

Logic "0" ≤ 0.8 V

Logic "1" \ge 2.4 V



DG412

OFF

ON

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Temp Range	Package	Part Number				
DG411/DG412						
- 40 to 85 °C	16-Pin Plastic DIP	DG411DJ DG411DJ-E3				
		DG412DJ DG412DJ-E3				
- 40 to 85 °C		DG411DY DG411DY-E3 DG411DY-T1 DG411DY-T1-E3				
	16-Pin Narrow SOIC	DG412DY DG412DY-E3 DG412DY-T1 DG412DY-T1-E3				
DG413						
- 40 to 85 °C	16-Pin Plastic DIP	DG413DJ DG413DJ-E3				
	16-Pin Narrow SOIC	DG413DY DG413DY-E3 DG413DY-T1 DG413DY-T1-E3				

ABSOLUTE MAXIMUN	I RATINGS			
Parameter		Limit	Unit	
V+ to V-		44		
GND to V-		25		
VL		(GND - 0.3) to (V+) + 0.3	V	
Digital Inputs ^a , V _S , V _D		(V-) -2 to (V+) + 2 or 30 mA, whichever occurs first		
Continuous Current (Any Terminal)		30	mA	
Peak Current, S or D (Pulsed at 1 ms, 10 % duty cycle)		100	- MA	
Storage Temperature	(AK, AZ Suffix)	- 65 to 150	°C	
Slorage temperature	(DJ, DY Suffix)	- 65 to 125		
	16-Pin Plastic DIP ^c	470		
Power Dissipation (Package) ^b	16-Pin Narrow SOIC ^d	600	mW	
	16-Pin CerDIP ^e	900		
	LCC-20 ^e	900		

Notes:

a. Signals on S_X, D_X, or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC Board.

c. Derate 6 mW/°C above 25 °C.

d. Derate 7.6 mW/°C above 75 °C.

e. Derate 12 mW/°C above 75 °C.



SPECIFICATIONS ^a									
	Unl	Test Conditions Unless Specified V+ = 15 V, V- = - 15 V	Temp ^b	Тур ^с	A Suffix - 55 to 125 °C		D Suffix - 40 to 85 °C		
Parameter	Symbol	$V_{\rm L} = 15 \text{ V}, V_{\rm IN} = 2.4 \text{ V}, 0.8 \text{ V}^{\rm f}$			Min ^d	Max ^d	Min ^d	Max ^d	Unit
Analog Switch					I				•
Analog Signal Range ^e	V _{ANALOG}		Full		- 15	15	- 15	15	V
Drain-Source On-Resistance	r _{DS(on)}	V+ = 13.5 V, V- = - 13.5 V I _S = - 10 mA, V _D = ± 8.5 V	Room Full	25		35 45		35 45	Ω
Switch Off Leakage Current	I _{S(off)}	V+ = 16.5, V- = - 16.5 V	Room Full	± 0.1	- 0.25 - 20	0.25 20	- 0.25 - 5	0.25 5	
	I _{D(off)}	$V_D = \pm 15.5 V, V_S = \pm 15.5 V$	Room Full	± 0.1	- 0.25 - 20	0.25 20	- 0.25 - 5	0.25 5	nA
Channel On Leakage Current	I _{D(on)}	V+ = 16.5 V, V- = -16.5 V $V_S = V_D = \pm 15.5 V$	Room Full	± 0.1	- 0.4 - 40	0.4 40	- 0.4 - 10	0.4 10	
Digital Control				_		_			
Input Current, V _{IN} Low	۱ _{IL}	V _{IN} under test = 0.8 V	Full	0.005	- 0.5	0.5	- 0.5	0.5	μA
Input Current, V _{IN} High	I _{IH}	V _{IN} under test = 2.4 V	Full	0.005	- 0.5	0.5	- 0.5	0.5	μ. τ
Dynamic Characteristics									•
Turn-On Time	t _{ON}	R_L = 300 Ω, C_L = 35 pF	Room Full	110		175 240		175 220	
Turn-Off Time	t _{OFF}	$V_{S} = \pm 10$ V, See Figure 2	Room Full	100		145 160		145 160	ns
Break-Before-Make Time Delay	t _D	DG413 Only, V _S = 10 V R _L = 300 Ω , C _L = 35 pF	Room	25					
Charge Injection	Q	$V_g = 0 V, R_g = 0 \Omega$ $C_L = 10 nF$	Room	5					pC
Off Isolation ^e	OIRR	R _L = 50 Ω, C _L = 5 pF,	Room	68					
Channel-to-Channel Crosstalk ^e	X _{TALK}	f = 1 MHz	Room	85					dB
Source Off Capacitance ^e	C _{S(off)}		Room	9					
Drain Off Capacitance ^e	C _{D(off)}	f = 1 MHz	Room	9					pF
Channel On Capacitance ^e	C _{D(on)}		Room	35					
Power Supplies			•						
Positive Supply Current	l+	V+ = 16.5 V, V- = - 16.5 V V _{IN} = 0 or 5 V	Room Full	0.0001		1 5		1 5	
Negative Supply Current	l-		Room Full	- 0.0001	- 1 - 5		- 1 - 5		μA
Logic Supply Current	ار		Room Full	0.0001		1 5		1 5	μ, ι
Ground Current	I _{GND}		Room Full	- 0.0001	- 1 - 5		- 1 - 5		

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SPECIFICATIONS FOR UNIPOLAR SUPPLIES ^a									
		Test Conditions			A Suffix		D Suffix		
		Unless Specified			- 55 to	125 °C	- 40 to	85 °C	
		V+ = 12 V, V- = 0 V							
Parameter	Symbol	$V_{L} = 5 V, V_{IN} = 2.4 V, 0.8 V^{f}$	Temp ^b	Тур ^с	Min ^d	Max ^d	Min ^d	Max ^d	Unit
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full			12		12	V
Drain-Source	~	V+ = 10.8 V,	Room	40		80		80	
On-Resistance	r _{DS(on)}	$I_{S} = -10 \text{ mA}, V_{D} = 3 \text{ V}, 8 \text{ V}$	Full			100		100	Ω
Dynamic Characteristics			•			•			
Turn-On Time	t _{ON}		Room	175		250		250	
	-010	$R_{L} = 300 \Omega, C_{L} = 35 pF$	Hot			400		315	
Turn-Off Time	tOFF	$V_{S} = 8$ V, See Figure 2	Room	95		125		125	ns
	011		Hot			140		140	110
Break-Before-Make	t _D	DG413 Only, V _S = 8 V	Room	25					
Time Delay	-0	$R_L = 300 \Omega$, $C_L = 35 pF$	ricom	20					
Charge Injection	Q	$V_{g} = 6 V, R_{g} = 0 \Omega, C_{L} = 10 nF$	Room	25					рС
Power Supplies						•			
Positive Supply Current	l+		Room	0.0001		1		1	
Toshive Supply Current	1+		Hot			5		5	
Negative Supply Current	-		Room	- 0.0001	- 1		- 1		
		V+ = 13.5 V, V _{IN} = 0 or 5 V	Hot		- 5		- 5		μA
Logic Supply Current	١L		Room	0.0001		1		1	μ, ,
Outon	L		Hot			5		5	
Ground Current	I _{GND}		Room	- 0.0001	- 1		- 5		
	Gite		Hot		- 5		-		

Notes:

a.Refer to PROCESS OPTION FLOWCHART.

b.Room = 25 °C, Full = as determined by the operating temperature suffix.

c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

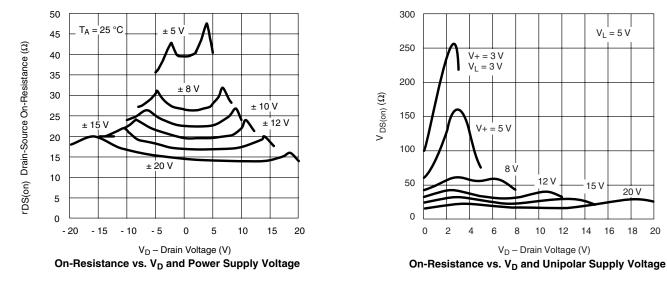
d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

e.Guaranteed by design, not subject to production test.

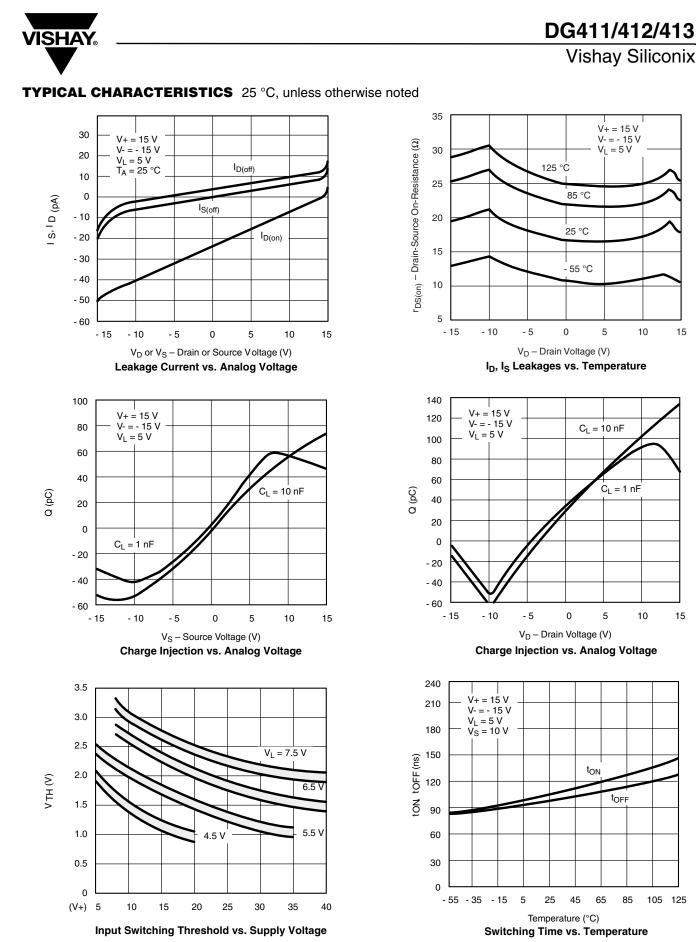
f. V_{IN} = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





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15

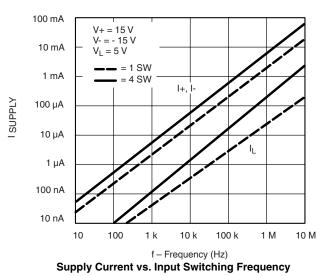
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DG411/412/413

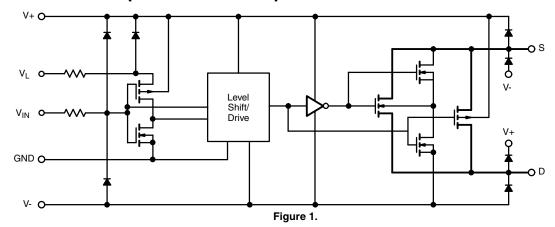
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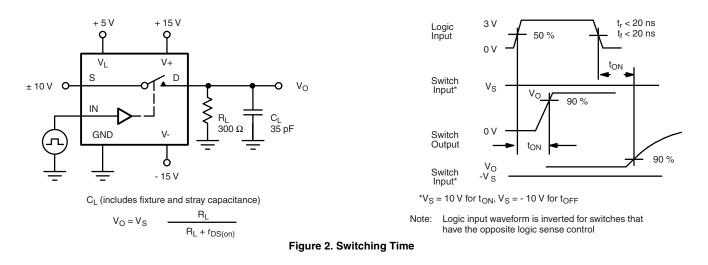
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



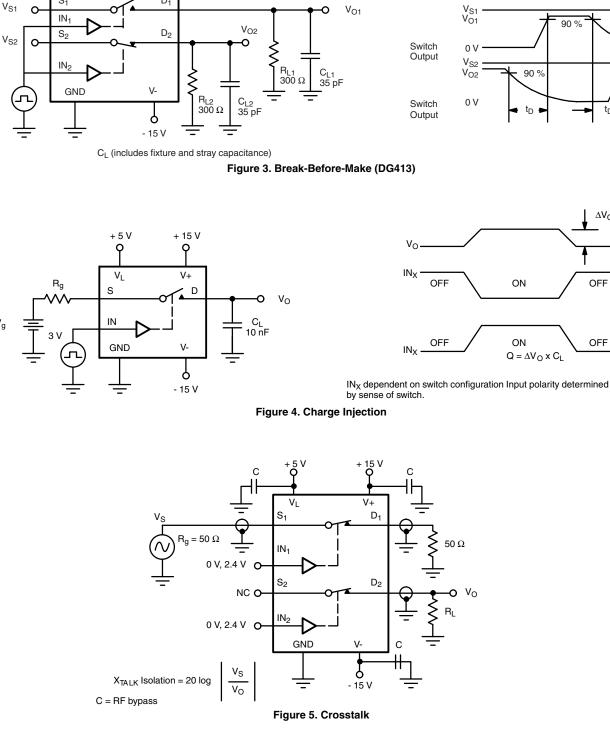
SCHEMATIC DIAGRAM (TYPICAL CHANNEL)



TEST CIRCUITS



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TEST CIRCUITS

 V_{S1}

O

+ 5 V

Q

 V_{L}

S₁

+ 15 V

Q

V+

.

C

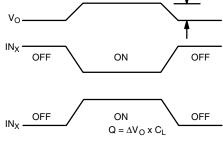
 D_1

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t_D

 ΔV_{O}

S-71241-Rev. E, 25-Jun-07



Logic Input

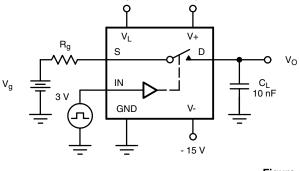
 V_{O1}

റ

3 V

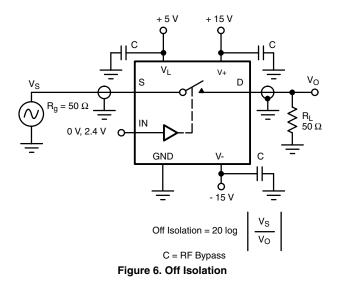
0 V

50 %



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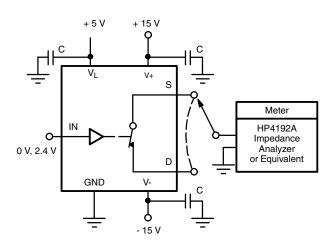


Figure 7. Source/Drain Capacitances

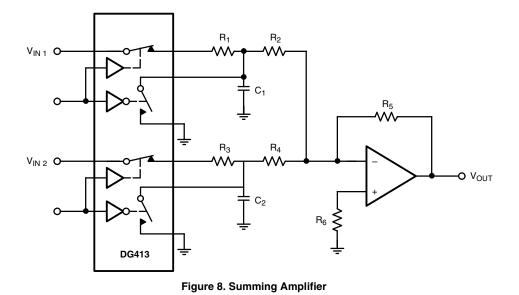
APPLICATIONS

Single Supply Operation:

The DG411/412/413 can be operated with unipolar supplies from 5 V to 44 V. These devices are characterized and tested for unipolar supply operation at 12 V to facilitate the majority of applications. In single supply operation, V+ is tied to V_L and V- is tied to 0 V. See Input Switching Threshold vs. Supply Voltage curve for V_L versus input threshold requirments.

Summing Amplifier

When driving a high impedance, high capacitance load such as shown in Figure 8, where the inputs to the summing amplifier have some noise filtering, it is necessary to have shunt switches for rapid discharge of the filter capacitor, thus preventing offsets from occurring at the output.



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